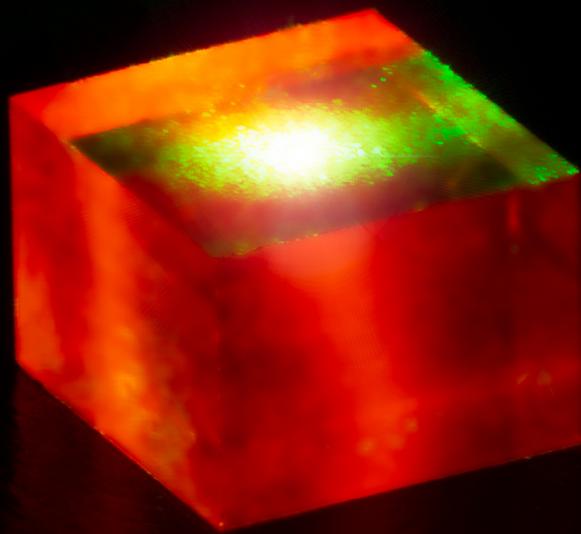

DNV™ Series

DNV™ B1 and DNV™ B14

Unlocking next generation quantum technologies

Perfectly imperfect diamonds,
uniquely designed for quantum
applications



elementsix™

DE BEERS GROUP

Advancing diamond quantum technologies

As part of our diamond portfolio grown by chemical vapour deposition (CVD), Element Six offers two quantum grades of single-crystal diamond that contain deliberate and controlled levels of nitrogen-vacancy (NV) centres, fabricated using our patented processes.

The resulting diamond NV (DNV) centres provide researchers with a unique solid-state platform with spin qubits that can be initialised and read out with long qubit lifetimes at room temperature. These properties stem from diamond's structure and strong covalent bonds.

DNV™ B1 and DNV™ B14

Element Six's DNV™ B1 and DNV™ B14 products are ideal for those interested in employing NV ensembles for DC & AC magnetic field sensing, masers, RF detection, gyroscopes and quantum demonstrators.

These grades of diamond are designed to provide the end-user with a uniform distribution of NV spin centres, in a small chip that may be readily integrated into a quantum device or employed in research experiments.

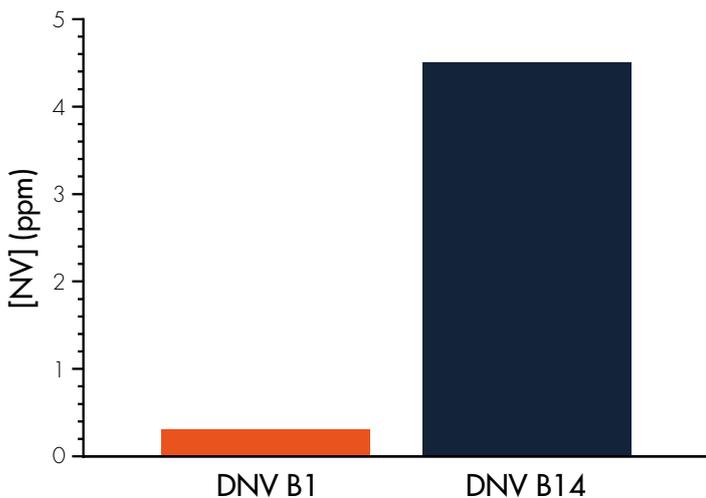


Figure 1: DNV B1 and DNV B14 in terms of [NV]

DNV B14 has a more than 10-times higher NV density (refer to Figure 1) compared to DNV B1. This difference in NV concentration ([NV]) is reflected in the contrasting colour of the two materials; DNV B1 samples are light pink, whereas DNV B14 has an intense purple colouration (Figure 2).



Figure 2: DNV B1 (left) and DNV B14 (right) CVD diamond samples

Due to the differing levels of [NV] and residual [N] the two types of material have varying spin characteristics. The typical inhomogeneous transverse coherence time (T_2^*) is of order $1 \mu\text{s}$ for DNV B1, which is reduced to $0.5 \mu\text{s}$ for DNV B14 (see Figure 3). Hahn echo measurements measure a factor of 20 higher T_2 in DNV B1 samples (of order $200 \mu\text{s}$ vs $10 \mu\text{s}$).

These values of [NV], T_2 and T_2^* mean the two materials lend themselves to different sensing modalities/applications. For example, the greatly increased Hahn-echo T_2 for DNV B1 means it is suited to AC magnetometry, whereas the increased [NV] in DNV B14 and only moderate reduction in T_2^* results in DNV B14 being applicable for DC-sensing magnetometry experiments.

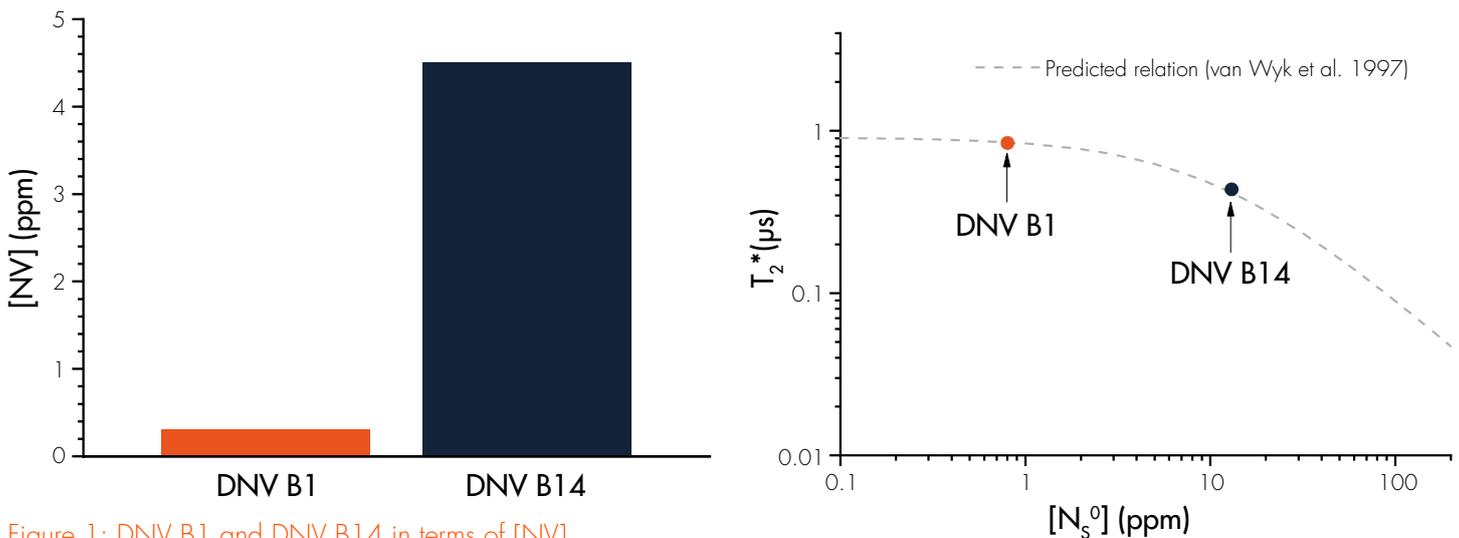


Figure 3: Spin coherence vs. nitrogen concentration (van Wyk et al. (1997). J. Phys. D: Appl. Phys. 30, 1790)

The choice of material also depends on device-design considerations, such as the amount of laser power used or how the microwaves are delivered, due to the differing densities of NV defects.

Specifications and tolerances	Values	
Crystallography	Major {100} polished faces	
Crystallographic orientation (miscut)	< +/-3°	
Typical dimensions	3 mm x 3 mm x 0.5 mm	
Edge features	< 0.2 mm	
Roughness, Ra	< 10 nm	
¹³ C	1.1%	

Quantum properties	DNV B1	DNV B14
Typical [N _s ⁰] (before treatment)	800 ppb	13 ppm
Typical [NV]	300 ppb	4.5 ppm
Typical spin coherence time T ₂ [*]	1 μs	0.5 μs
Typical spin coherence time T ₂	200 μs	10 μs

Further reading

1. Markham, M. and Twitchen, D. (2020). **The diamond quantum revolution**. Physics World 33, 39
2. Zhang, H. et al. (2018). Little bits of diamond: Optically detected magnetic resonance of nitrogen-vacancy centers. American Journal of Physics 86, 225. <https://doi.org/10.1119/1.5023389>

Contact us

E technologies@e6.com
T +44 1344 638 200
W e6.com

© Element Six, 2021

Element Six, the E6 logo and DNV are trade marks of the Element Six Group.